



PATENT APPLICATION
Docket No. 9898-291
Client No. SS-17916-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Eun-Sung SEO and Hyun-Soon JANG

Serial No. 10/620,015 Examiner: Vu, Quang D.

Conf. No. 9260

Filed: July 14, 2003 Art Unit: 2811

For: LAYOUT STRUCTURE OF FUSE BANK OF SEMICONDUCTOR
MEMORY DEVICE

Mail Stop AMENDMENT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Responsive to the Office Action dated June 3, 2004, enclosed is an amendment in the above-identified application.

The fee has been calculated as shown below.

CLAIMS AS AMENDED					
For:	Number After Amendment	Previous Number	Extra	Rate	Additional Fee
Total Claims	20	20		x \$18 =	\$0
Independent Claims	5	5		x \$86 =	\$0
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT					\$0

- ☒ Return Post Card
☒ Any deficiency or overpayment should be charged or credited to deposit account number 13-1703.

Customer No. 20575

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.

Julie L. Reed
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I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Mail Stop Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Date: September 2, 2004

Angie C. Farr
Angie C. Farr



JPW 2811

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AMENDMENT

Responsive to the Office Action, dated June 3, 2004, please amend the application as follows.

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.